3V dual pre/power amplifier BA3516

The BA3516 is a dual pre/power amplifier designed for headphone stereo applications. It operates off a 3V supply. The preamplifier block can be direct-coupled, and the power amplifiers do not require bootstrap capacitors, and use a fixed-gain negative feedback circuit to reduce the number of external components required and allow compact and reliable set designs.

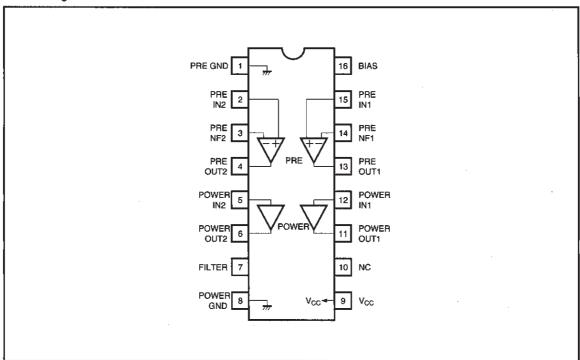
Applications

3V headphone stereos and 3V radio cassette players.

Features

- 1) Dual preamplifiers and power amplifiers on one chip.
- 2) Preamplifiers can be direct coupled.
- 3) Bootstrap capacitors for the power amplifiers are not required.
- 4) The preamplifiers have high gain (78dB), low noise (1 μ Vrms), and low distortion (0.03%).
- 5) The power amplifiers have high output (40mW \times 2), low noise (80 μ Vrms), and low distortion (0.5%).

Block diagram



330

■Absolute maximum ratings (Ta = 25°C)

Parameter	Symbol	Limits	Unit V	
Supply voltage	Vcc	4.5		
Power dissipation	Pd	1000*1	mW	
Operating temperature	Topr	-25~75	င	
Storage temperature	Tstg	−55 ~125	ా	

^{*1} Reduced by 10.0mW for each increase in Ta of 1°C over 25°C.

●Recommended operating conditions (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	Vcc	1.8	2.4	3.6	

●Electrical characteristics (unless otherwise specified Ta = 25°C, Vcc = 2.4V and f= 1kHz)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions	Measuremen Circuit
Quiescent circuit current	lα	_	8	14	mA	V _{IN} =0V _{rms}	Fig.1
<preamplifier>R_L=10kΩ</preamplifier>							-'
Open-circuit voltage gain	Gvo	72	78		dB	V ₀ =-10dBm	Fig.1
Maximum output voltage	Vом	200	300	_	mV _{ms}	THD=1%	Fig.1
Total harmonic distortion	THD₁	_	0.03	0.15	%	V ₀ =0.2V _{ms} , NAB33dB	Fig.1
Input conversion-noise voltage	V _{NIN}	_	1.0	1.8	μ Vrms	Rg=2.2kΩ, BPF20~20kHz	Fig.1
Ripple rejection	RR ₁	40	47	_	dB	V _{AR} =-20dBm, f=100Hz NAB33dB, Rg=2.2kΩ	Fig.1
Input bias current	l _{B1}	_	60	300	nA	V _{IN} =0V _{ms}	Fig.1
$<$ Power amplifier $>$ R _L =16 Ω		_					
Rated output	Роит	30	40	_	mW	THD=10%	Fig.1
Closed-circuit voltage gain	Gvc	34	36	38	dB	V _{IN} =-40dBm	Fig.1
Total harmonic distortion	THD₂		0.5	1.5	%	P ₀ =1mW	Fig.1
Output noise voltage	V _{NO}	_	80	125	μ Vrms	Rg=0Ω, BPF20~20kHz	Fig.1
Ripple rejection	RR₂	35	48	_	dB	V _{RR} =-20dBm, f=100Hz, Rg=0Ω	Fig.1
Input resistance	Rin	21.4	30	38.6	kΩ	_	Fig.1
Input bias current	l _{B2}	-	22	80	nA	V _{IN} =0V _{rms} , Rg=10kΩ*1	Fig.1
Channel balance	СВ	_	0	0.7	dB	V ₀ =-10dBm	Fig.1
<preamplifier +="" amplifier<="" power="" td=""><td>< connection</td><td>as per a</td><td>plication</td><td>example c</td><td>ircuit≫</td><td></td><td></td></preamplifier>	< connection	as per a	plication	example c	ircuit≫		
Channel separation	CS _{L-R}	27	37	_	dB	Pre-Rg=2.2kΩ, VR Max.*2 Single channel Power-Vo=-5dBm BPF20~20kHz	Fig.1
Leakage from preamp to power amp for signal leak VR Min.	SL	_	-63	-57	dBm	Power-Rg=0 Ω *3 When both channels are operating Pre Vouτ=-12dBm	Fig.1

^{*1} $I_{B2} = \frac{V_{B2}}{10k\Omega} \times \frac{4}{3}$

VB2: Voltage at each end of Rg= $10k\Omega$.

st 2 0dB attenuation from the preamplifier output to power amplifier input.

^{*3} Power amplifier signal source impedance is $0\,\Omega$

●Measurement circuit

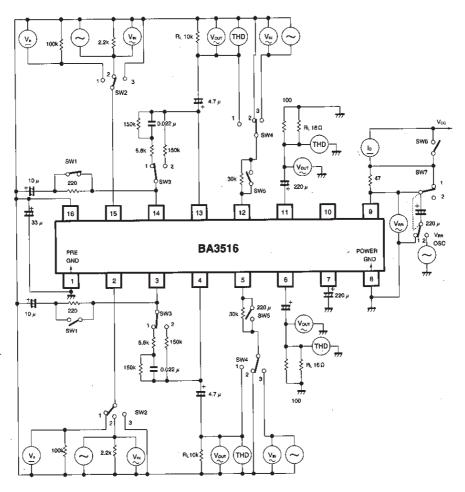


Fig. 1

Application example

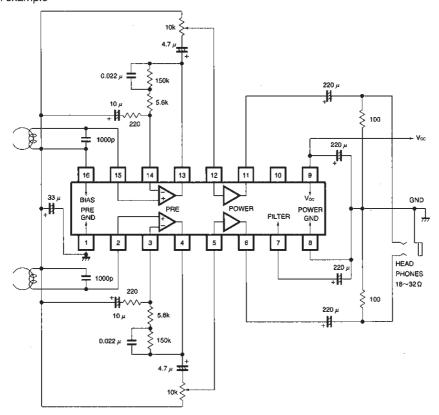
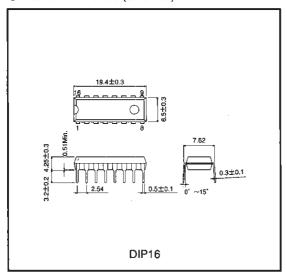


Fig. 2

External dimensions (Unit: mm)



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